



1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Lead Free/RoHS Compliant (Note 1)

Mechanical Data

- Case: SOD-123
- Plastic Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Polarity: Cathode Band
- Leads: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Marking: Date Code and Type Code, See Page 3
- Type Code: SL
- Ordering Information: See Page 3
- Weight: 0.01 grams (approximate)



SOD-123							
Dim	Min	Max					
А	3.55	3.85					
В	2.55	2.85					
С	1.40 1.70						
D	—	1.35					
E	0.45	0.65					
E	0.55 Typical						
G	0.25	—					
н	0.11 T	ypical					
J	_	0.10					
	0°	8°					
All Dimensions in mm							

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V	
RMS Reverse Voltage	V _{R(RMS)}	28	V	
Average Rectified Output Current $@ T_L = 90^{\circ}C$	Io	1.0	А	
Repetitive Peak Forward Current t _p 1ms, 0.5	I _{FRM}	1.5	А	
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	25	А	
Power Dissipation (Note 2)	Pd	450	mW	
Typical Thermal Resistance Junction to Ambient (Note 2)	R ja	222	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +125	°C	

Notes: 1. No purposefully added lead.

2. Device mounted on FR-4 PC Board, 2"x2", 2 oz. Copper, single sided, Cathode pad dimensions 0.75"x1.0", Anode pad dimensions 0.25"x1.0".



Iectrical Characteristics @ T _A = 25°C unless otherwise specified								
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	40			V	I _R = 1.0mA		
Forward Voltage	VF			0.320 0.450 0.750	V	$I_F = 0.1A$ $I_F = 1.0A$ $I_F = 3.0A$		
Reverse Leakage Current (Note 3)	I _R		10 1 15 1.5	1.0 10 50 2 75 3	mA mA μA mA μA mA	$ \begin{array}{l} V_R = 40V, \ T_A = \ 25^\circ C \\ V_R = 40V, \ T_A = \ 100^\circ C \\ V_R = 4V, \ T_A = \ 25^\circ C \\ V_R = 4V, \ T_A = \ 100^\circ C \\ V_R = 6V, \ T_A = \ 25^\circ C \\ V_R = 6V, \ T_A = \ 100^\circ C \end{array} $		
Total Capacitance	CT		50		pF	$V_R = 4V$, f = 1.0MHz		

Notes: 3. Short duration pulse test used to minimize self-heating effect.



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Ordering Information (Note 4)

Device	Packaging	Shipping
1N5819HW-7-F	SOD-123	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



SL = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

Year		2001	2002	2 2	2003	2004	200	5	2006	2007	2008	2009
Code		М	N		Р	R	S		Т	U	V	W
Month	Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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